

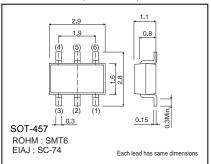
Features

- 1) Two digital class transistors in a SMT package.
- 2) Up to 500mA can be driven.
- 3) Low $V_{\text{CE(sat)}}$ of drive transistors for low power dissipation.

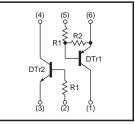
•Package, marking, and packaging specifications

Part No.	IMD10A
Package	SMT6
Marking	D10
Code	T108
Basic ordering unit (pieces)	3000

•Dimensions (Unit : mm)



●Absolute maximum ratings (Ta=25°C)



•Equivalent circuit

DTr₁

Parameter	Symbol	Limits	Unit
Supply voltage	Vcc	-50	V
Input voltage	Vin	-5 to +5	V
Collector current	lc	-500	mA

DTr₂

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	50	V
Collector-emitter voltage	Vceo	50	V
Emitter-base voltage	Vево	5	V
Collector current	lc	100	mA

Total

Parameter	Symbol	Limits	Unit	
Power dissipation	Pd	300(TOTAL)	mW *	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

* 200mW per element must not be exceeded.

•Electrical characteristics (Ta=25°C)

DTr₁

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
land the literation	VI(off)	-	-	-0.3	v	Vcc=-5V , Io=-100µA	
Input voltage	VI(on)	-1.5	-	—		Vo= -0.3V , Io= -100mA	
Output voltage	VO(on)	_	-0.1	-0.3	V	Io= -100mA , II= -5mA	
Input current	li	_	_	-25	mA	VI=-2V	
Output current	IO(off)	_	_	-0.5	μΑ	Vcc=-50V , VI=0V	
DC current gain	Gi	68	_	—	-	Io=-100mA , Vo=-5V	
Transition frequency	fт	_	200	_	MHz	Vce= -10V , Ie=50mA , f=100MHz *	
Input resistance	R1	70	100	130	Ω	-	
Resistance ratio	R2 / R1	80	100	120	-	-	

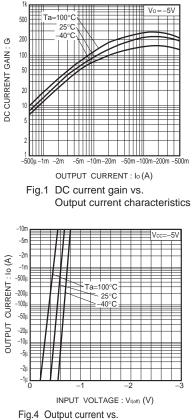
* Transition frequency of the device.

DTr₂

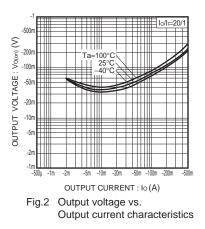
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage	ВУсво	50	_	_	V	Ic=50μA	
Collector-emitter breakdown voltage	BVCEO	50	_	_	V	Ic=1mA	
Emitter-base breakdown voltage	ВУево	5	_	_	V	Ιε=50μΑ	
Collector cutoff current	Ісво	_	_	0.5	μΑ	Vcb=50V	
Emitter cutoff current	Іево	_	_	0.5	μA	VEB=4V	
Collector-emitter saturation voltage	VCE(sat)	_	_	0.3	V	Ic=10mA , IB=1mA	
DC current transfer ratio	hfe	100	250	600	_	Vce=5V , Ic=1mA	
Transition frequency	f⊤	_	250	_	MHz	Vce=10V , Ie= -5mA , f=100MHz *	
Input resistance	R1	7	10	13	kΩ	—	

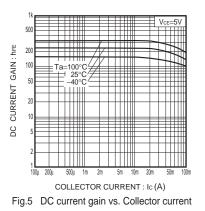
* Transition frequency of the device.

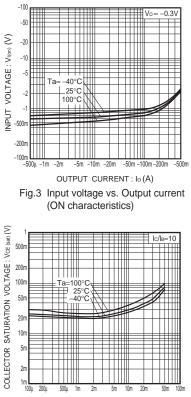
•Electrical characteristic curves











COLLECTOR CURRENT : Ic (A) Fig.6 Collector-emitter saturation voltage vs. Collector current

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